

## Supporting Information

# MOF-Derived $\alpha$ -NiS Nanorods on Graphene as an Electrode for High-Energy-Density Supercapacitors

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## **Basic characterizations**

The crystallographic structures of the materials were obtained using a Bruker D8 advanced diffractometer powder X-ray diffraction (PXRD) with an X'celerator module and Cu K $\alpha$  ( $\lambda = 1.54050 \text{ \AA}$ ) radiation at room temperature, with a step size of  $10^\circ$  in  $2\theta$ . Raman spectra were obtained using a Renishaw spectromicroscopy system equipped with a  $20\times$  objective optical microscope. The microstructure and morphology were examined by using a field emission scanning electron microscope (FE-SEM) (Hitachi S-4800) equipped with a Bruker Quantax energy dispersive spectrometer (EDS). Transmission electron microscope (TEM) images were taken on FEI Tecnai F20 and F30 microscopes. Elemental analysis was performed on a Vario EL Elemental Analyzer. Surface characterization of elemental electronic states was measured by X-ray photoelectron spectroscopy (XPS) (Kratos Axis Ultra Imaging Photoelectron Spectrometer). The instrument was equipped with a monochromatic Al-K $\alpha$  X-ray source ( $h\nu=1468.7 \text{ eV}$ ). The nitrogen isotherms of the materials were measured within the pressure range 0-1 atm at 77K using a Quadrasorb system from a Quantachrome Autosorb-IQ gas adsorption analyzer. Applying the Brunauer-Emmett-Teller (BET) model and quenched solid state functional theory (QS-DFT) to these isotherms, specific surface areas and pore sizes distribution were determined for each material.

## **Electrochemical measurement**

The electrochemical measurements were carried out by using a Zahner Zennium electrochemical workstation in case of both three-electrode configuration and two-electrode device. For the working electrode of three-electrode system, a mixture slurry containing of 80 wt% active materials, 10 wt% Super P and 10 wt% PTFE binder was prepared then rolled with the assistance of ethanol to form a uniform film with a typical areal mass of approximately  $2.5 \text{ mg cm}^{-2}$ . The film

electrode was then pressed between two nickel foam, and dried under vacuum at 80 °C for 12 h. A platinum mesh electrode and an Ag/AgCl electrode prefilled with saturated KCl aqueous solution were used as the counter and the reference electrodes, respectively. The cyclic voltammograms (CV) were acquired in a potential range between 0 and 0.55 V at different scan rates, and the charge-discharge processes were performed between 0 and 0.5 V at different current densities in a 2 M KOH aqueous electrolyte. Based on the galvanostatic discharge curve, the specific capacity  $Q$  ( $\text{C g}^{-1}$ ) of the battery-type R-NiS/rGO was calculated as follows:

$$Q = i_m \Delta t \quad (\text{S1})$$

where  $i_m = I/m$  ( $\text{A g}^{-1}$ ) is the current density,  $m$  is the mass of the active material,  $\Delta t$  (s) is the discharge time.

The cyclic stability was evaluated by galvanostatic charge-discharge measurements at a current density of 20  $\text{A g}^{-1}$ .

The electrochemical measurements of the two-electrode device containing R-NiS/rGO as positive electrode and C/NG-A as negative electrode (-1-0 V) with separator of MPF30AC-100 (Nippon Kodoshi Corporation, Kochi, Japan) in a split test cell (MTI Corporation) configuration were carried out in a 2 M KOH electrolyte. The negative electrode film was prepared with the same method described above with 90 wt% C/NG-A and 10 wt% PTFE binder. The mass ratio of positive electrode to negative electrode is determined according to charge balance theory ( $q^+ = q^-$ ). Based on the CV results from three-electrode system,

$$q = \int i m dV / v \quad (\text{S2})$$

where  $q$  represents the charge,  $m$  is the mass of the active material, and  $\int idV/v$  is the integral area from CV.

In order to achieve charge balance,  $m^+ \cdot \left(\int \frac{idV}{v}\right)_+ = m^- \cdot \left(\int \frac{idV}{v}\right)_-$ , thus,

$$m^+ : m^- = \left(\int \frac{idV}{v}\right)_- : \left(\int \frac{idV}{v}\right)_+ \quad (\text{S3})$$

The CV was acquired in a potential range between 0 and 1.6 V at different scan rates, and the charge-discharge processes were performed by cycling the potential from 0 to 1.6 V at different current densities. The cyclic stability was evaluated by galvanostatic charge-discharge measurements at a current density of 20 A g<sup>-1</sup>.

The specific capacitance was calculated from the galvanostatic charge-discharge measurements using the following equation,

$$C = \frac{2i_m \int V dt}{V^2 \Big|_{V_i}^{V_f}} \quad (\text{S4})$$

$C$  represents the galvanostatic charge-discharge (GCD) specific capacitance.  $\int V dt$  is the integral current area, where  $V$  is the potential with initial and final values of  $V_i$  and  $V_f$ , respectively.  $i_m = I/m$  is the current density, where  $I$  is the current and  $m$  is the mass of active materials.

The energy density  $E$  (Wh kg<sup>-1</sup>) and power density  $P$  (W kg<sup>-1</sup>) in Ragone plot were calculated with the following equations,

$$E = \frac{1}{2} \cdot \frac{C \cdot \Delta V^2}{3.6} \quad (\text{S5})$$

$$P = 3600 \cdot \frac{E}{\Delta t} \quad (\text{S6})$$

Where C is the specific gravimetric capacitance (F g<sup>-1</sup>), ΔV is the potential window (V), and Δt is the discharge time (S).

### Density functional theory (DFT) calculation

Density functional theory calculations were performed within VASP (Vienna ab-initio Simulation Package) {Efficient iterative schemes for ab initio total-energy calculations using a plane-wave basis set}. The generalized gradient approximation parameterized by Perdew, Burke and Ernzerhof under projector augmented wave function {Generalized gradient approximation made simple} was applied to pseudo-potentials of Ni and S. Three surface slabs were constructed and visualized via VESTA, with a 15 Å vacuum space for each one. (110), (101) and (102) slabs have 64, 128 and 160 atoms per supercell. Energy was sampled by 1 × 1 × 1 reciprocal space mesh centered at gamma point. To ensure convergence, an energy cut-off of 400 eV was chosen to reach the energy and force accuracy of 1E-6 eV and 0.01 eV/ Å. Energy correction {Periodic boundary conditions in ab-initio calculations} due to polarization of surface slab was considered for all three slabs, as well as charged hydroxyl, i.e. OH<sup>-</sup>. The surface energy was calculated via the equation shown below:

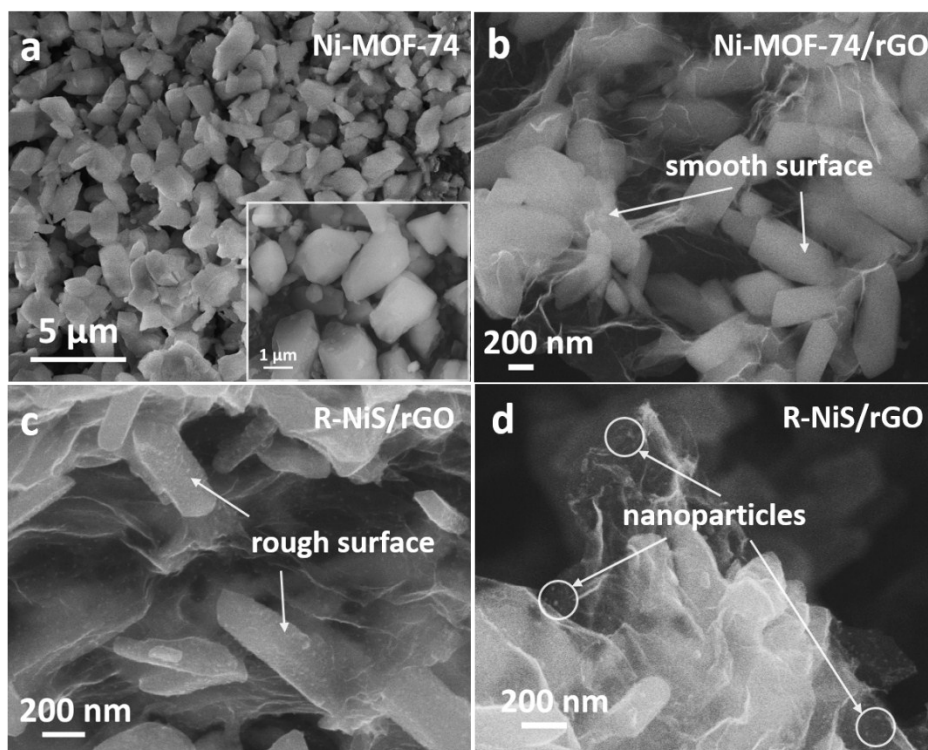
$$E_{sur} = (E_{slab} - nE_{unit - bulk})/2A \quad (\text{S7})$$

where  $E_{sur}$  is the surface energy,  $E_{slab}$  and  $E_{unit - bulk}$  is the total energy of slab super-cell and bulk unit-cell,  $n$  is the multiplicity of slab cell over unit cell,  $A$  is surface area of the slab.

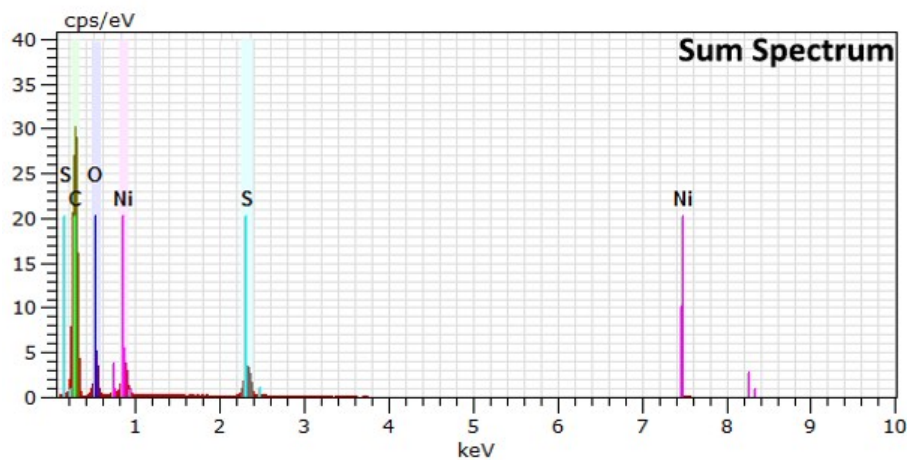
The adsorption energy of OH<sup>-</sup> was calculated via the equation shown below:

$$E_{ads} = E_{*-OH} - E_{slab} - E_{OH^-} \quad (\text{S8})$$

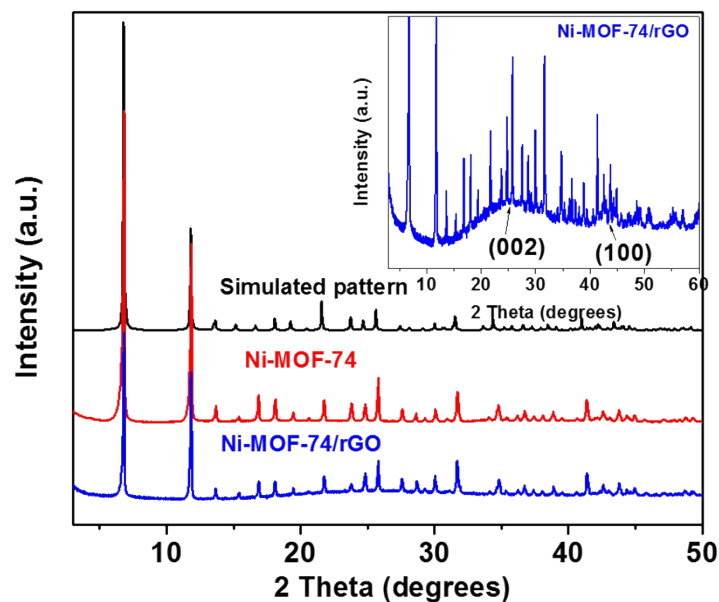
where  $E_{*-OH}$  is the total energy of NiS slab with hydroxyl group adsorbed on one surface Ni site,  $E_{slab}$  is the total energy of slab super-cell, and  $E_{OH^-}$  is the total energy of an isolated  $\text{OH}^-$ .



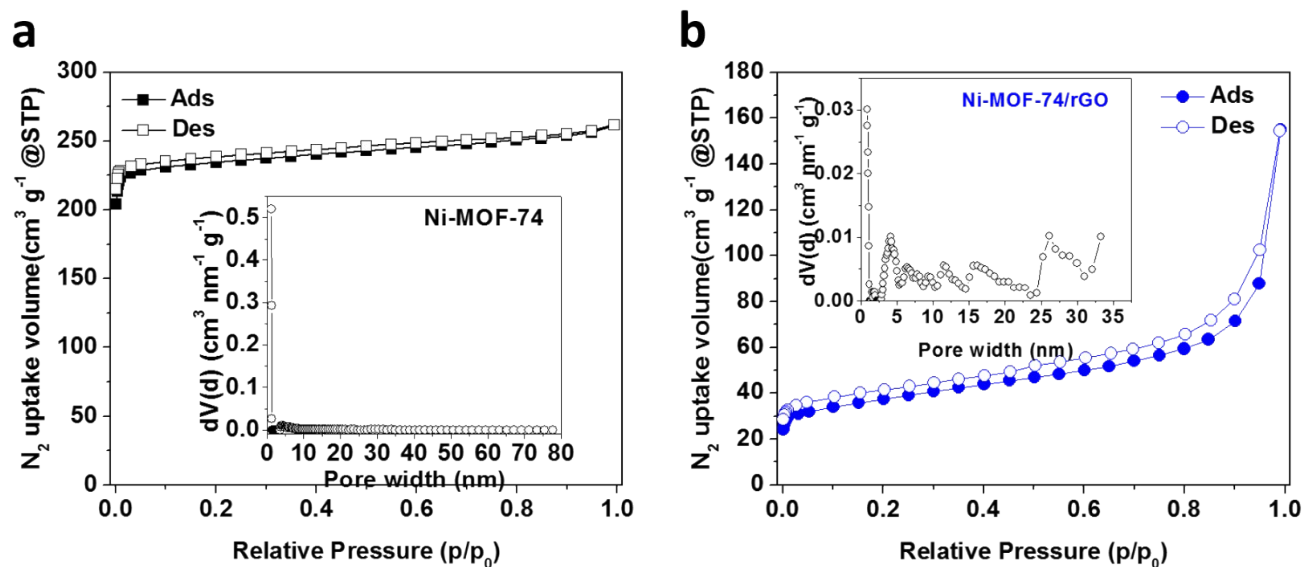
**Figure S1.** SEM images of (a) Ni-MOF-74 bulk materials, (b) Ni-MOF-74/rGO hybrid nanostructure, and (c-d) R-NiS/rGO nanostructures. The arrows in (b), (c), and (d) indicate different surface morphologies between Ni-MOF-74/rGO and R-NiS/rGO.



**Figure S2.** EDS sum spectrum of the R-NiS/rGO.

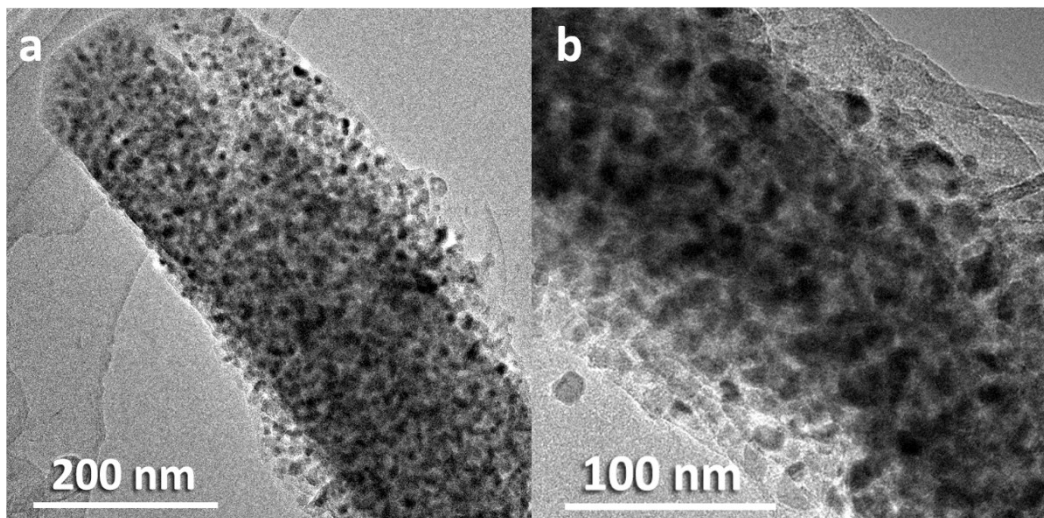


**Figure S3.** PXRD patterns of the as-synthesized Ni-MOF-74, Ni-MOF-74/rGO, and the simulated Ni-MOF-74, inset is the enlarged Ni-MOF-74/rGO XRD pattern.

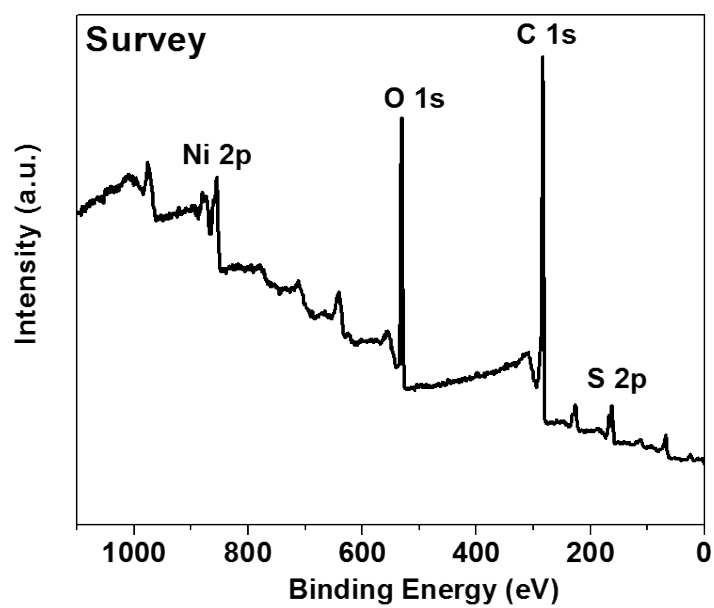


**Figure S4.** N<sub>2</sub> adsorption-desorption isotherms and corresponding pore size distribution plot (inset) of a) Ni-MOF-74 and b) Ni-MOF-74/rGO.

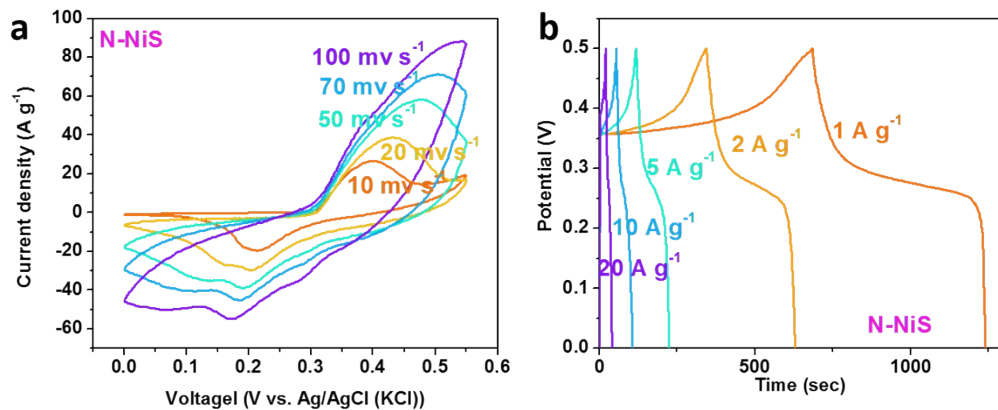




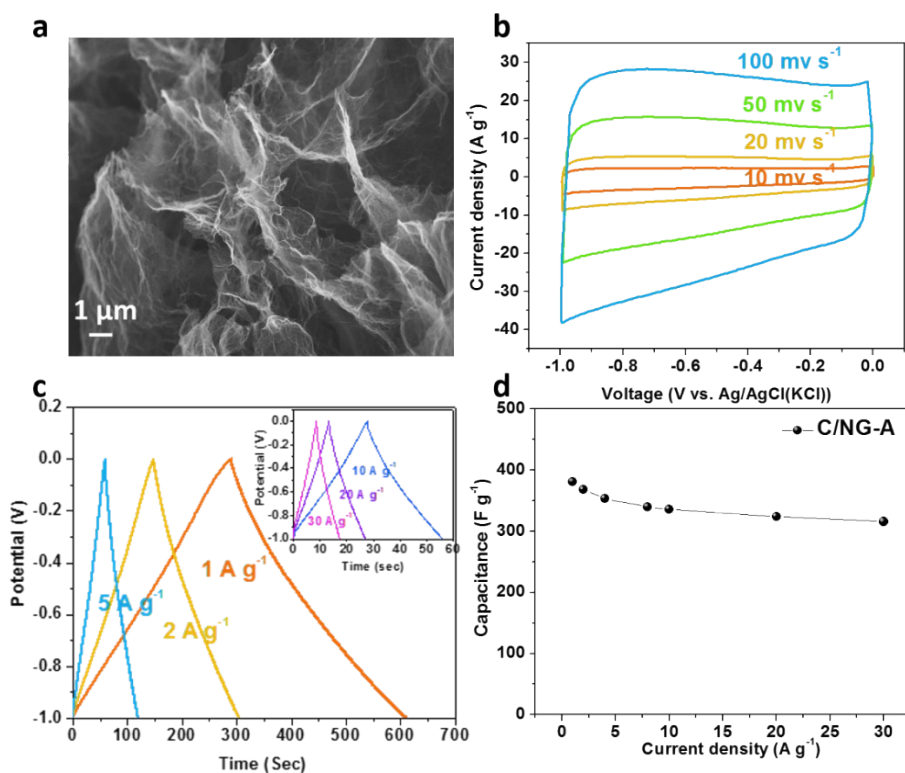
**Figure S5.** TEM images of the NiS nanorod decorated on the graphene sheets.



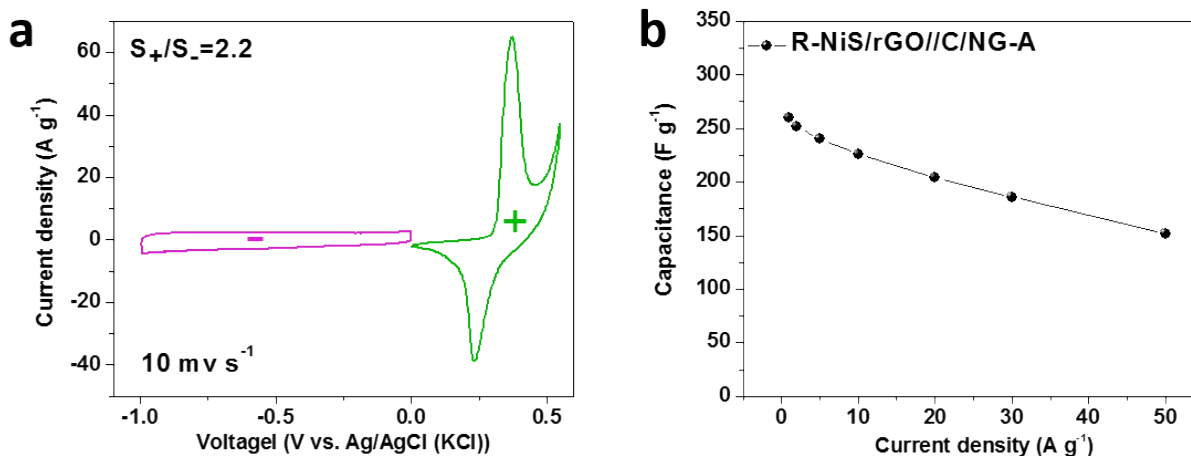
**Figure S6.** XPS survey spectrum of the R-NiS/rGO.



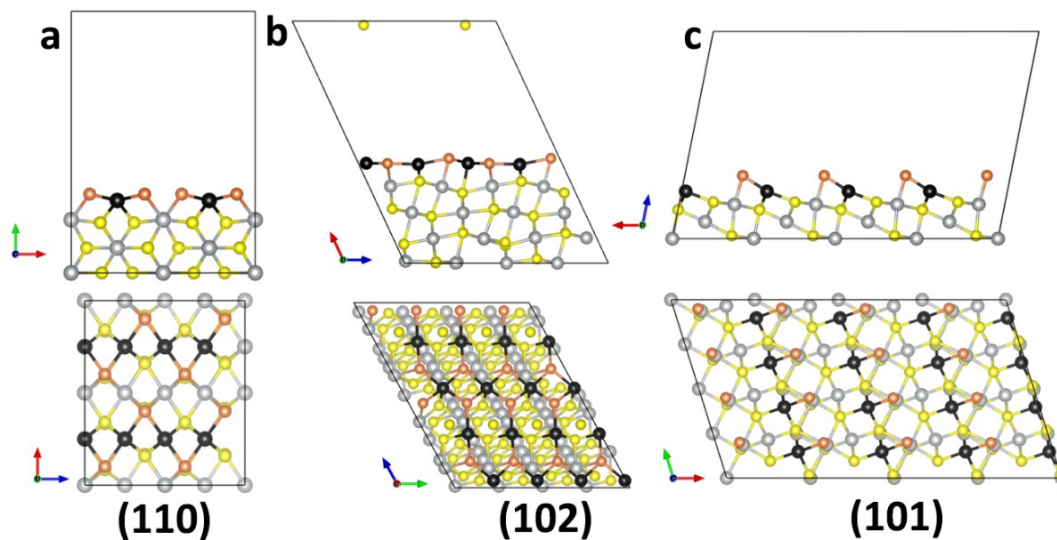
**Figure S7.** a) CV curves of N-NiS, b) GCD curves of N-NiS.



**Figure S8.** a) SEM image of the C/NG-A, b) CV curves of the C/NG-A at different scan rates, c) GCD curves of the C/NG-A at different current densities, and d) Specific capacitances and rate capability of the C/NG-A.



**Figure S9.** a) CV comparison between the positive and negative electrodes of the R-NiS/rGO//C/NG-A device, b) Specific capacitances and rate capability of the R-NiS/rGO//C/NG-A hybrid supercapacitor.



**Figure S10.**  $\alpha$ -NiS slabs: (a) (110), (b) (102), and (c) (101) with surface exposed to vacuum. Black and copper balls are surface Ni and S atoms, while silver and yellow ones are the rest Ni and S atoms. Red, green and blue arrows are lattice vectors a, b and c. Upper pictures are side view; lower picture is vertical view.